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# Total-energy-based structure prediction for d (A IN iC o)

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One may predict a quasicrystal structure starting from electrons and quantum mechanics, as approximated by interatom ic pair potentials calibrated with ab-initio total-energy calculations, combined with the experim entally known com position and lattice constants. Here we report our progress on the \basic N i" decayonal phase  $d(A \downarrow_0 N i_{21} C \circ_9 . A \text{ tom ic con-}$ gurations are represented as decorations of (possibly) random tilings. Our method was Monte Carlo simulation using both lattice-gas hops by atom s and tile- ip rearrangem ents, eventually followed by molecular dynamics and relaxation of the atom positions. Initially allowing the greatest freedom of atom positions, we observed nearly determ inistic structural rules and enforced these as constraints involving larger tiles; this procedure was repeated at the next level of modeling. In crude and prelim inary form , the e ective H am iltonian for tile-tile interactions is known, which is needed for further sim ulations to infer the long-range order. Our atom ic arrangem ents in the 20 A decagonal cluster are com pared with three structure m odels based on recent experim ents.<sup>1</sup>

# I. IN TRODUCTION

This paper reports on early results of a program to determ ine the structure of a quasicrystal { speci cally  $d(A \ N \ iC \ o)$  { strictly from energetics, without use of di raction data. A lm ost all of the work was performed by M M .and M W .with their coauthors, and is reported in Ref. [1], but the present account is tilted towards the particular interests of C L H.

We have focused on the thermodynamically stable and highly ordered \Basic Nickel" subphase of decagonald (A IN iC o) [2,3], of composition approximately A  $l_{0:70}$  N  $i_{0:21}$  C  $o_{0:09}$ . Our ultimate objective is to predict the structure on the basis of total energy; though the gross aspects of the structure are clear from diraction, there are many am biguous or controversial details, and there is no understanding for the quasicrystal's special stability and simplicity at this composition. In particular, we wish to identify the sites of the transition metal (\TM ") components N i and C o, which are indistinguishible to (ordinary) X -rays or electrons [4{8].

In a sense, the most dicult problem of crystal chem istry is to predict which structure a given composition will adopt, even if one has an exact and tractable H am iltonian for the total energy (e.g. by pair potentials) { for this necessarily involves a comparison with an innity of possible structures. The only irreproachable m ethod is a m athem atical proof, which is feasible in rare cases with short-range interactions, e.g. close-packing of hard spheres, or the two-dimensional \binary-tiling" quasicrystal (a toy m odel) [9]. A naive, brute-force approach would be to cool (in simulation) from the melt, and see which structures emerge; but this is prone to fail for a complicated material, since the accessible times are so short that it will get stuck in a glassy disordered con guration. Even when a quasicrystal emerges, as with D zugutov's toy potentials [10], the system m ay have found a merely metastable ordered state for kinetic reasons: indeed, the stable phase in this case turned out to be a simple bcc packing [11].

### II. DECORATION MODELS

W e represent the quasicrystal structure as a decoration of disjoint tiles. There are several reasons for doing so, rather than as a irrational cut through a ve-dim ensional hypercrystal. Based in real space, this representation is easier to visualize and som ewhat more tractable, technically, than the hypercrystal approach. For example, shifts of the atom s from ideal (tiling-vertex) sites are param etrized by just a nite set of real num bers, like the coordinates in a crystal unit cell. A decoration description { particularly in the decagonal case { naturally lends itself to a hierarchy of supertilings, which are presum ably involved in the modulations which distinguish some of the subphases in the d (A IN iC o) phase diagram [3]. Furtherm ore, most hyperspace structures which have been de ned using discrete acceptance dom ains, e.g. Ref. [4], can be translated into tiling-decoration language.

Decoration models are uniquely suited to a correct modeling of chemical disorder (including vacancies) in a quasicrystal. Of course, a hyperspace t to B ragg data can incorporate mixed occupation of a site type, but it is highly implausible (from the view point of the structural energy) that the occupations of neighboring sites

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vary independently of each other. If the occupations are strongly correlated, then the mean structure may dier signi cantly from any particular real structure; this matters e.g. because the electronic structure is quite sensitive to the TM-TM contacts in  $d(A \ N \ ic \ o)$  [12]. The tiling decoration is a very convenient way to account for such occupation correlations, by ascribing the random ness to the tiles and not the decoration. The ultimate criterion of a decorated model { xing e.g. the appropriate size of tile { is that the ensemble of allowed tilings corresponds one-to-one with the ensemble of low energy arrangements in an atom istic model.

A decoration description replaces the independent real coordinates of m any atom s by tiling degrees of freedom, which are discrete and m any tim es few er. W hen the decoration is determ inistic and disjoint (each atom bound to a particular tile or tile-related geom etric ob ject), then the atom s' interaction energies can be expressed as a function solely of the tile con guration, called the \tile H am iltonian" H tile. This facilitates faster M onte C arlo simulations, on the comparatively few tile degrees of freedom, in order (i) to reveal supertilings in the process of discovering the atom ic structure, as in this work; (ii) to predict di use scattering, or (iii) eventually to measure the phason elastic constants (which govern the di use wings surrounding Bragg peaks.) A m ed with a reliable H  $_{\rm tile}$  , one can also simulate three-dimensional samples to obtain quantitative estimates of the perfection of the long-range order and the strength of di use di raction.

This approach m ay also be the easiest way to resolve, for a particular stable quasicrystal, whether or not it is entropically stabilized. It is stabilized by energy favoring a quasiperiodic state if H <sub>tile</sub> happens to im plement the Penrose h atching rules'. That almost occurs in d (A L uC o), as modeled with potentials like those used in the present work [13].

O ur challenge, then, is to nd the decoration rule and the tile-packing constraints without any bias, apart from the above-m entioned assumptions about the lattice constants. A caveat to keep in mind is that the results will probably be quite sensitive to the exact composition and number density.

### III. IN PUTS: POTENTIALS AND CONSTRAINTS

The main input to our calculations is a set of atom – atom pair potentials  $V_{ij}(r)$  for species i and j, six distinct functions in the case of a ternary alloy. They are given by M oriarty's \generalized pseudopotential theory" (GPT) [14{16], a system atic expansion of the total energy as a sum  $E_0 + E_1 + E_2 + :::$ , where the  $E_n$  term depends on n atom s, but we use only the n = 2 term s. The rst-neighbor well of the raw  $V_{TM TM}$  is unphysically deep (which would be canceled by  $E_3$  in the system atic theory). Therefore our  $V_{TM TM}$  potentials were empirically modi ed, by tting a short-range repulsive correction so as to m atch all the forces in a full density-functional calculation on a sm all (50 atom ) approxim ant ofd (A N iC o) [16]. There is strong support that  $\operatorname{ourV}_{ij}(r)$  have the correct r dependence and relative strength, since they predict the A I-C o and A I-N iphase diagram s pretty well [15] (as a function of concentration at T = 0); how - ever the termary A I-N i-C o phase diagram was not attempted. On the basis of the simulated melting tem - perature and phonon spectra, we do suspect that our potentials are 30% stronger than the reality.

Like the sim ilar A HTM potentials of Phillips, Zou, and C arlson, used earlier in R efs. [13] and [17], the G P T potentials depend in plicitly on the net valence electron density, and exhibit strong \Friedel oscillations" as a function of distance (tails decaying as  $\cos(2k_F r + )=r^3$ ). For example,  $V_{A \, \mathrm{IT\,M}}$  (r) and  $V_{TM \, \mathrm{TM}}$  (r) show four prominent m inim a in the range r 8:5 A; such m inim a are quite im portant in deciding the structure [17,18].

Notice that  $V_{A \mid A \mid}(r)$  is practically zero after its hard core radius 2:9 A : there is not even a nearest-neighbor well, just a shoulder on the tail of the hard-core. The  $V_{A IIM}$  potentials have very deep nearest-neighbor wells: this creates the illusion of a TM -TM repulsion, but really TM -TM neighbors are avoided mainly to make more room for Al in the TM coordination shells. However, at roughly 30% TM content, som e TM -TM contacts are unavoidable; they are all N i-N i, since VA LC o has a deeper wellthan  $V_{A N i}$ . Finally, the  $V_{TM TM}$  potentials have their deepest well at second-neighbor ( 42A) distances. The consequence of all this is that the TM atom s form a rather rigid and som ew hat uniform ly spaced network [19], while A latom s m ove rather freely to follow the potential wells or troughs created by the TM arrangement. (See Sec.V formorediscussion).

O ur use of these potentials in poses som e limitations. We om itted the n = 0 term, which depends only on the valence electron density, and is the largest contribution to a m etal's total energy. Hence we can make valid com - parisons only between structures with (practically) the same valence electron density. We cannot meaningfully predict the lattice constants. Nor can we even expect the quasicrystal phase to be globally stable according to our potentials, since they m ight spuriously favor phase-separation.

In view of the above-mentioned pitfalls for a bruteforce approach, we adopted as a second input the experimental lattice constants [2]: the stacking period is c = 4.08 A and the quasilattice constant in the decagonalplane is  $a_0 = 2.45 \text{ A}$ . We only seek the lowest energy am ong arrangements on this fram ework. This highly constraining assumption still permits a vast ensemble of possible structures. O urm ethods are a m ix of tile- ip M onte C arlo, atom hopping M onte C arlo, relaxation of atom ic positions, and m olecular dynam ics. O ur procedure is rst to discover the favorable low-energy m otifs through M onte C arlo annealing, then to rem ove unnecessary degrees of freedom, and repeat, producing successively m ore constrained m odels. Having fewer degrees of freedom the latter are m uch faster to sim ulate at low tem peratures. At the end, we can investigate the e ects of letting atom s depart from ideal sites.

The initial stage of our exploration stacks two independent small (edge  $a_0$ ) Penrose rhom bic tilings, in a vertical space of one lattice constant c = 4.08 A and the only allowed atom sites are on vertices. A manageable size was 50 atom s on 72 candidate sites, initially on a good Penrose-tiling approximant; periodic boundary conditions are used in all directions (and at all stages of exploration). The atom s { initially chosen to approxin ate the experimental density and composition of the Ni-rich \Basic Ni" phase { hop as a lattice gas on these sites. This allows su cient freedom for the atoms, if they \want", to adopt any of the decagonal structure m odels { with stacking period c = 4 A { that were hypothesized at one time or another [20,21]. The Monte Carlo moves permit swaps of the species between two nearby sites (\vacant" is a special case of species!), as well as \tile ips" which reshue the three rhom bi in a fat or thin hexagon in the sam e layer.

A fter thism odel is slow ly cooled to zero tem perature, if the initial composition was rightly chosen, one obtains a one-layer H exagon-B oat-Star (HBS) tiling of edge length a<sub>0</sub>, with a two-layer decoration in which the allowed sites lie over vertices of the Penrose rhom bi (into which HBS tiles may be decomposed) or an additional site in each Fat rhom bus. This decoration places Al atom s over the HBS vertices (even and odd vertices alternate between even and odd layers). Isolated Co atom s sit over each Boat and Star tile center, ringed by possible Al sites; in the Star at most two Alcan be present, out of veideal sites in this ring. Particularly characteristic are the vertical zigzag chains, with Ni in each layer (appearing as N iN i pairs in Fig. 1), over the interior of every H exagon tile. However, NiNimay be replaced by CoAlin some places. Decorating a tiling with the same H/B/S ratios as the quasiperiodic Penrose tiling yields an ideal com position A  $l_{0:700}$  N  $l_{0:207}$  C  $O_{0:093}$  and atom ic volum e 14.16 A<sup>3</sup>. This composition coincides with the experimental Basic Niphase, but the num ber density of atom s is at least 5% greater than in experiment.

For the next stage ofm odeling, to discover larger-scale regularities, the sm all HBS tiles which emerged from the initial stage are elevated to fundam ental objects, either with a rigid decoration or with some atoms xed and others form ing a lattice gas. The allowed tile ips are reshu ings of fat hexagons of the underlying rhom bus

tiling, provided the result is a valid HBS tiling and conserves the atom content. Additionally the Alpair inside the Startile can rotate among ve allowed orientations. From this simulation, it emerges that the Hexagon tiles containing Ni chains only touch tip-to-tip, so that the angles relating them are multiples of 72. In fact, (see Fig. 1) the long axes of the Hexagons form edges of an HBS supertiling with an in ated edge length  ${}^{2}a_{0}$ , where  $(1 + {}^{5})=2$ .

# V.THE 20 A DECAGON CLUSTER

We now compare our results with well-known structure models, organizing the discussion around the fam ous 20 A diameter decagon cluster, which is prominent in electron-microscope in ages and in most diraction renements as well. (The ideal decagon diameter is actually 2  ${}^{3}a_{0}$ .) Such decagons indeed appear in our structures [22]; Fig. 1 is centered on one of them . Z-contrast in ages, in which the intensity is a direct projection of atom s weighted by squared atom ic number, reveal the TM positions [6,7]; the TM (and most Al) positions proposed by Ref. [7] are practically the same as in our version of the cluster.

For a more detailed com parison, we focus on three recent structural studies [4{6]. All of these, and our sim – ulation, agree on the following details of the projection: (1) the outer decagon (edge length  ${}^{2}a_{0}$ ) has Alon each vertex and a pair of TM atom s on each edge, which we identify as Ni. (2) A middle decagon (edge  $a_{0}$ ) has TM atom s on each vertex, which we identify as Co. (3) An inner decagon (edge  $a_{0}$ ) has Alon each vertex. (4) In the center, the 10-fold sym metry is broken and a sort of isosceles triangle is observed, with one TM (we say Co) at the unique corner and pairs of TM (we say NiNi) at the base corners. The cluster is evident in Ref. [4] on the right side of their Fig. 7, as a combination of a Boat tile + 2 H exagon tiles, just as in our Fig. 1.

Detail (4) is somewhat controversial, since some decagon in ages have non-triangular centers. Indeed, the density m aps from the re nem ent of Ref. [5] show six strongly TM sites at the center of m any (but not all) of the 20 A decagons. We ascribe this to stacking ips between one layer and the next layer (see Sec. V I), seen in projection, as in the right-side decagon of Fig. 2.

The simulations we described up till now implicitly assumed a strict c = 4.08 A periodicity in the stacking direction, neglecting (like so much other modeling) the fact that decagonal quasicrystals are three-dimensional. To obtain the con guration in Fig. 2, we increased the periodicity to 2c, i.e. two HBS layers, which initially were the same tiling. First a tile- ip was made in one of the two HBS layers, then the tilings were decorated, annealed by MD, and relaxed to an energy minimum.

In a flh, controversial detail of the decagons, our model initially disagreed with experiments in which ev-

ery edge of the m iddle decagon shows a pair of A latom s. These sites form vertical zigzag chains, but they cannot all be occupied since they are separated by essentially the interlayer spacing c=2 = 2.08 A. In our xed-decoration m odel, then, these sites are occupied in only one atom layer, with separation c, so only one atom is visible on each edge. We found that, after m olecular dynamics (MD) at 1000K followed by relaxation, som e Al neighbors of the C o atom s shifted to the m iddle-decagon edges, which now present Al doublets in projection, in agreem ent with experiment.

To further understand what happens with these atom s, the tim e-average of the Alpositions during the MD simulation is shown in Fig. 3. Some 40% of Alatom s are rather delocalized, and would need a highly anisotropic Debye-W aller factor in a crystallographic t. [24] The vertical projection (Fig. 3 (a) show s, consistent with our rem arks on the potentials (Sec. III), that each Co atom in the m iddle decagon is surrounded by a potential trough in which Al atom s appear alm ost free to roll like ballbearings [25].

A slice along a vertical plane further clari es the A lbehavior: a second type of trough extends vertically, with a zigzag shape, and in fact connects with the circular troughs. In our simulations with a cell 2c in the verticaldirection, we found three A latom s appearing in each zigzag trough (per 2c, i.e. per 4 atom layers). Notice that the z displacement of two of these atom smakes the layer puckered, as is already known from diraction [5], and in plies a local cell-doubling along the c axis, sim ilar to the A  $l_{13}Fe_4$  or A  $l_{13}Co_4$  decagonal approxim ants.

The sym metry-breaking of the cluster interior was recently predicted from energies by a full ab-initio calculation [26]. They nd, from a quite di erent starting point than ours, the identical arrangement of the 5 A 1+ 5 TM atoms (per atom ic bilayer) found at the cluster's center. How ever, they rejected the possibility of A 1 doublets on the middle decagon edges without trying z relaxations, nor did they address C o/N iordering. We nd it striking that our mere pair potentials su ced to obtain the experimentally indicated form of symmetry breaking in the cluster center, while using no experimental input whatsoever regarding the positioning of A l relative to TM atoms.

## VI.TILE HAM ILTON IAN AND THREE-DIMENSIONAL STACK ING

To model a large, three-dimensional sample using a tile H am iltonian, we cannot dem and perfect periodicity in the z direction. (One reason is that the \entropic stabilization" explanation of quasicrystal order requires an extensive entropy.) So, we represent each bilayer of atom s by a distinct HBS tiling, and constrain adjacent tilings in the stack to di er by \stacking ips", which are exactly the same reshu ings that constitute our M onte C arlo tile- ips.

W ealso found (from simulations) that { among (sm all) HBS tilings in which H tiles form a network touching tip-to-tip { the in-plane tile H am iltonian is dom inated by interactions between H(N iN i)" tiles (H exagon tiles decorated by N iN i). Thus we suggest

$$H_{tile} = C_{72}N_{72} + E_{sf}N_{sf}$$
: (1)

where N  $_{72}$  is the number of H (N iN i) tile pairs related by a 72 rotation about their common tip, and N  $_{\rm sf}$  is the total number of stacking ips.

We tted  $c_{72} = 0.218 \text{eV}$  [1] from the simulation with ideal sites; this is positive since the 72 relation of H (N iN i) tiles creates intertile N iN i neighbors, and thus reduces the num ber of (favorable) A Nipairs. The structure m in im izes N<sub>72</sub> by arranging that in som e places, an H (N iN i) tile has one tip which contacts no other H (N iN i), and sees CoAl (at a 144 angle) in place of NiNi. That may be accomplished in two ways. If we re-allow latticegas hopping on the interior sites of the (sm all) HBS tiles, and properly adjust the stoichiom etry [1], we obtain the same old rigid decoration, except that a few H (CoAl) tiles appear, as illustrated in Fig. 1.0 n the other hand, if we retain the rigid N iN idecoration of sm all H tiles, the CoAlbelongs to the interior of a Boat tile, and the large HBS tiling acquires a fourth kind of tile (\Bow tie"), as in Fig. 4 (a) of Ref. [1].

Existing experiments can in principle measure E<sub>sf</sub>. The time-dependent local \phason" ips [27], observed at T 1200K by TEM through very thin samples of d(ALCuCo), can only occur by nucleating a \stacking ip" at one surface, which subsequently random -walks to the other surface. Video im ages [27] display an interm ediate state for a noticeable fraction { say 10% { of the time, so that with a sample thickness estimated at 100 A (25 bilayers), one would very roughly esti-03 eV in d(ALCuCo). It would be exciting m ate E <sub>sf</sub> if such observations could be analyzed quantitatively. In our simulation, with rigid atom s decorating ideal sites, 1:4 eV. However, relaxation (as in Fig. 2) nearly E<sub>sf</sub> cancels this energy  $\cos t$ , indeed  $E_{sf}$ 0.2 eV in very prelim inary results, which should not be compared with the experim ents on a di erent quasicrystal. (Physically,  $E_{sf} < 0$  probably implies a period 2c 8 Am odulation.)

### V II. D ISC U SSIO N

We nd it remarkable that, with quite sketchy experimental input, our simulations appear competitive with single-crystal di raction as a way of discovering this rather complex structure. This occurs despite the shortcom ings of the pair potentials { our om ission of 3-body terms, and the likelihood that the  $V_{A\,IT\,M}$  we use is stronger than the real one. Even if the connection to the m icroscopics is not quantitative, one may still obtain the large-scale order quite well: that depends mostly on

the tile H am iltonian (1) having the proper form, which is more robust than the num erical values of the coe cients.

It should also be pointed out that even in perfect potentials could be quite useful for augmenting a t of di raction data. A combination of energy and di raction data could overcom e m inor spurious features in renem ents [23].

O ur results strongly suggest that, in this alloy system, stability of the quasicrystal requires a ternary not only to tune the electron density, as in the H um e-R othery picture, but also because each species lls a particular type of site. Thus it would be highly desirable to explore some other composition regimes in simulations. The Co-rich \basic C o" subphase of d (A N iC o) would be of particular interest. It exhibits much stronger di use scattering than B asic N i, particularly halfway between the layers of B ragg peaks in reciprocal space, indicating a local tendency to doubling the c periodicity (8 A structures).

Our constraint that the atom s sit on ideal sites in the initial stage of energy optim ization has considerable potential to distort the conclusions. C learly, atom displacem ents have a very strong e ect so it is crucial to include these for a nalanswer. Sm all adjustments of position can gain as much energy as swaps of species, and in some cases the optimal sites may lie halfway between ideal sites, or between ideal layers { the so-called \puckered" layers W e do allow such relaxations in later stages, after determining a decoration, but it appears possible that a di erent decoration would be obtained, if we allowed relaxations in the early stages. This seems to be the most serious drawback of the lattice-gas approach [13] we used. Its advantages are that the system atic M onte Carlo exploration is not biased by its users' prejudices, and furtherm one it could readily be adapted to T > 0(the tem peratures at which the quasicrystalphase is stable). Nonzero tem perature probably a ects the result just as strongly as relaxed positions do.

W ithin the fram ework of pair potentials and tiledecoration representation of the structure, a di erent approach is possible [17], whereby relaxed sites are used in the main discovery process. To implement this so that only valid tile decorations get explored, one perform s relaxations with the decoration-equivalent atom s of a given class (\orbit") being constrained to m ove together. How ever, that m ethod is ad-hoc, depending on its users' educated guesses as to the tilings and decorations to be tried. Future work should strive to blend the best features of these two approaches to using decorations with potentials for the discovery of structures.

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- [19] This rationale for structural tendencies emphasizes second-neighbor TM -TM interactions, whereas R ef. [1] emphasized rst-neighbor A l-A land A l-TM interactions with A l atom s at ideal sites. Perhaps the best ternary structures evade \fustration", by being independently optim al for both TM -TM and A l-related potentials.
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present form ulation, the lattice-gas sites of R ef. [13] lay on a xed quasilattice. The quasilattice sites must be more densely placed in order to obtain comparable results without the freedom of tile ips.

- [22] The 20 A rings are commoner in images than in our simulations of single bilayers. One possible explanation is \stacking ips" between the layers. This was illustrated in Fig. 8 of R ef. [23], using the same d (A N iC o) structure reported in the present paper. Just a couple stacking ips, seen in projection, create an apparent decagon, and they also tend to symmetrize the appearance of the decagon interior.
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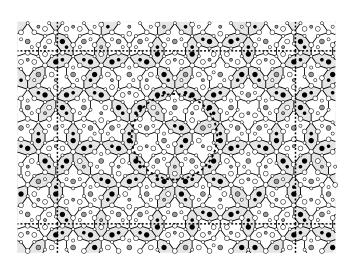
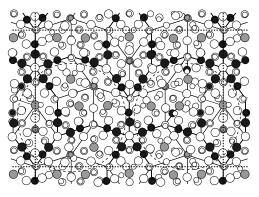


FIG.1. Lowest-energy con guration obtained from a simulation with variable occupancy interiors. Circles are colored with the following convention: empty=Al, gray=Co, black=N i; the size of the sym bol represents the z coordinate. Shaded sm all hexagon tiles, occupied by either N  $\mathbb{N}$  i pairs or A  $\mathbb{C}$  o pairs, form the edges of an HBS supertiling. D ashed circle indicates an 20 A decagon cluster. This is the sam e con guration as Fig.4(b) of R ef. [1].



F IG .2. Two bilayers (thickness 2c), with periodic boundary conditions in all directions, after a tile ip in one bilayer, followed by molecular dynam ics and relaxation to an energy m inim um . B lack lines are HBS supertile edges (length  $^{2}a_{0}$ ). The dashed circles are imperfect 20 A decagons { this cell is too sm all to contain complete ones.

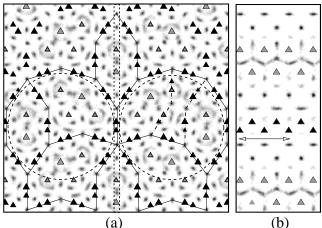


FIG. 3. Probability density of A l atom centers during a molecular dynam ics simulation of the same conguration as in Fig.2. TM locations are indicated by triangles, with the same coloring and size conventions as the previous gures. Edges of the large HBS tiles are marked by lines. (a) Projection onto xy plane. (b) Projection onto the yz plane of the narrow slab outlined by a dashed rectangle in (a). The pattern repeats with the z period 8 A. (Note this slice actually cuts through an H tile but not a 20 A cluster.)